

Molten Silicon Storage of Concentrated Solar Power with Integrated Thermophotovoltaic Energy Conversion



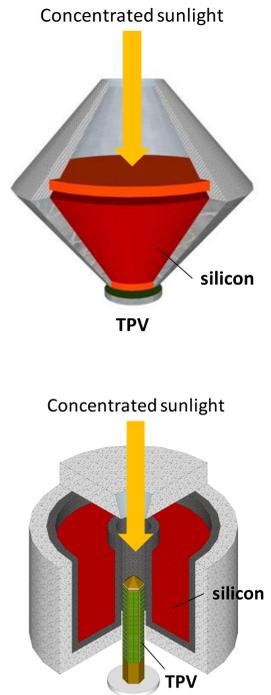
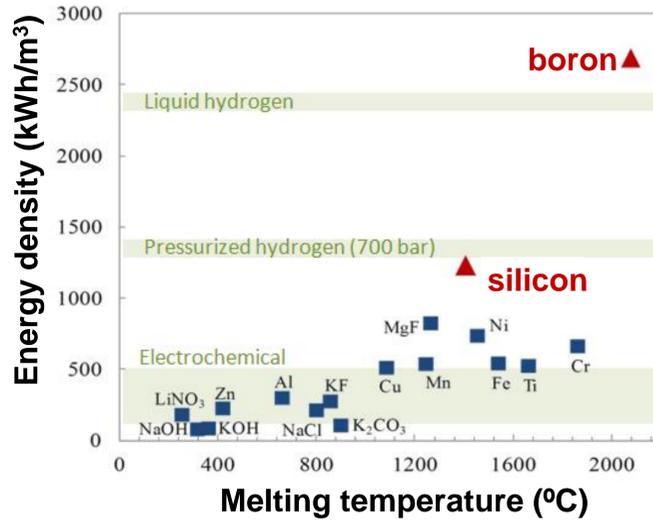
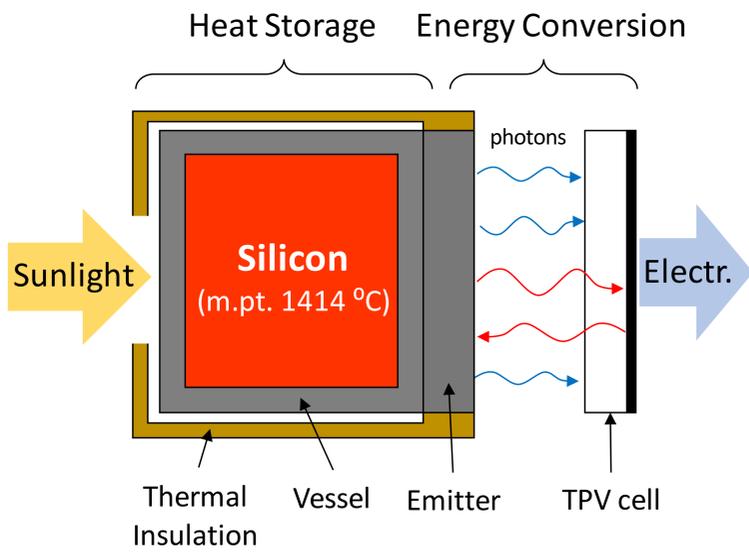
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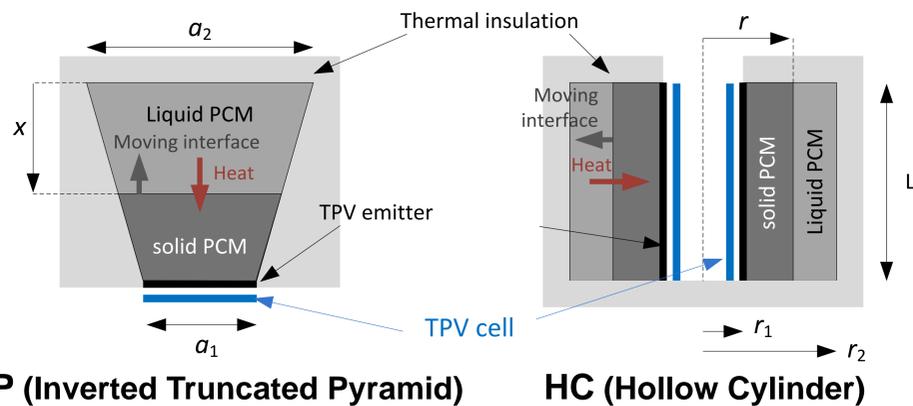
The Concept



- ✓ LHTES in molten silicon at **1414°C**
- ✓ **Thermophotovoltaic** (TPV) heat-to-power conversion

- ✓ More than **1000 kWh_{th}/m³** (10 x molten salts)
- ✓ Several **10's kW_e/m²** of TPV module area

Objective: Geometrical Optimization

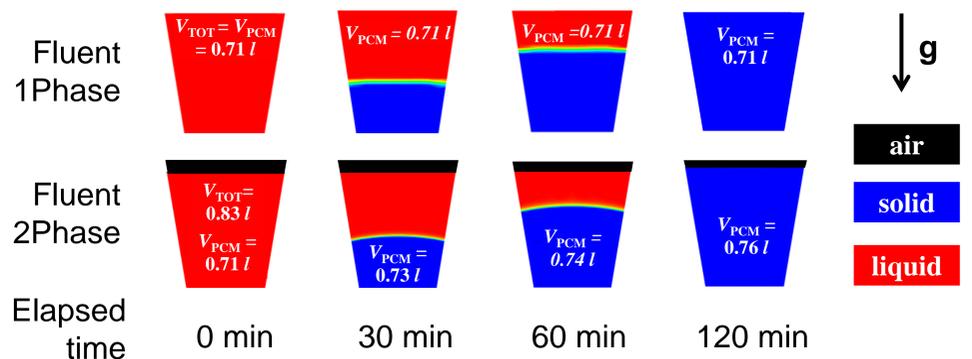
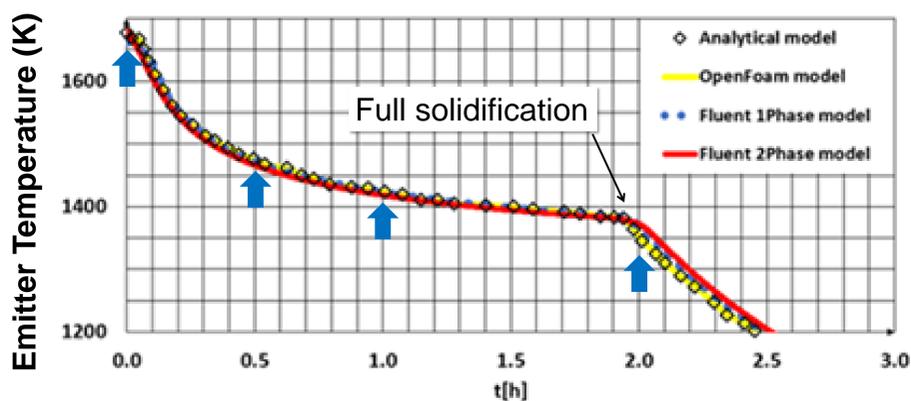


- ✓ Explore ITP and HC geometries using a quasi 1D-semi analytical model
- ✓ Parameters: **Tapering Ratio (A_1/A_2)** and **Length (L)**

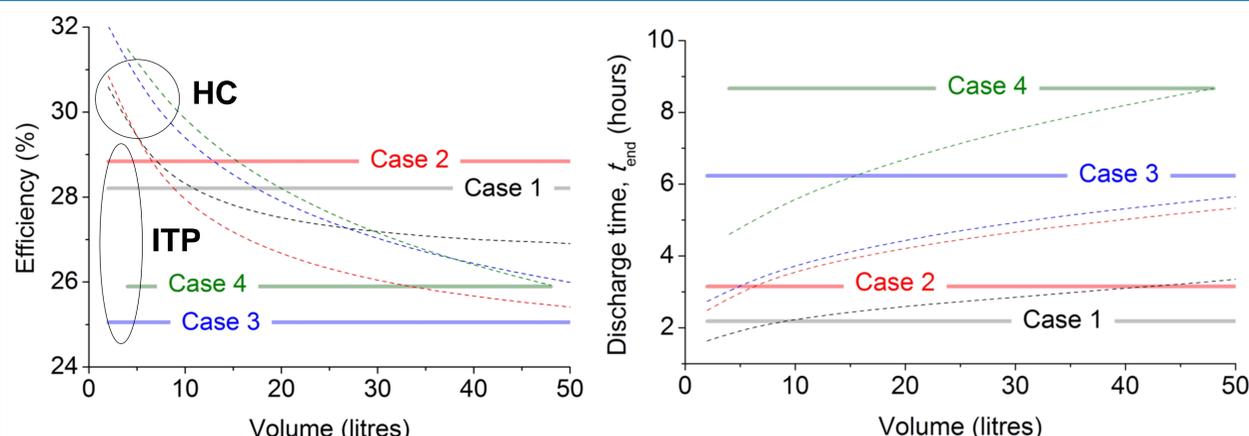
Case	ITP	HC
Case 1 ($L = 10$ cm)	$A_1/A_2 = 0.50$	$A_1^* = A_1, V^* = V$
Case 2 ($L = 10$ cm)	$A_1/A_2 = 0.25$	$A_1^* = A_1, V^* = V$
Case 3 ($L = 20$ cm)	$A_1/A_2 = 0.50$	$A_1^* = A_1, V^* = V$
Case 4 ($L = 20$ cm)	$A_1/A_2 = 0.25$	$A_1^* = A_1, V^* = V$

$A_1 = a_1^2 \quad A_2 = a_2^2 \quad A_1^* = 2\pi r_1 L \quad A_2^* = 2\pi r_2 L$

Models: Semi-Analytical Vs. CFD



Semi-Analytical Model Results



Optimum geometries

